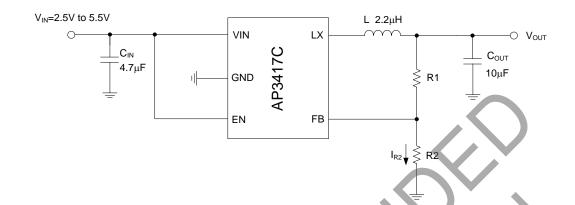


# **Typical Applications Circuit**



### **Component Guide**

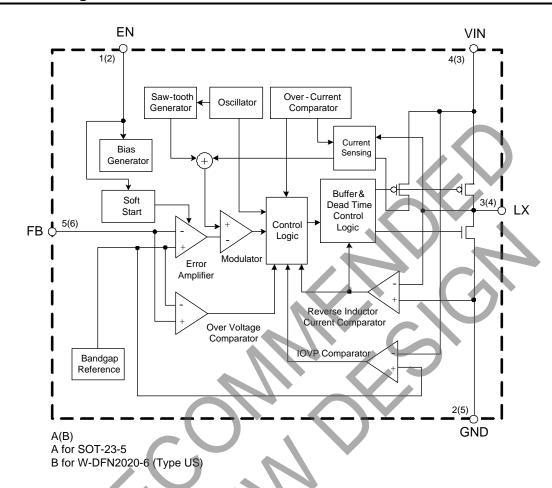
V <sub>OUT</sub> (V)	R1 (kΩ)	R2 (kΩ)	L (µH)
3.3	450	100	2.2
2.5	320	100	2.2
1.8	200	100	2.2
1.2	100	100	2.2
1.0	66	100	2.2

# **Pin Descriptions**

Pin N	umber		
SOT-23-5	W-DFN2020-6 (Type US)	Pin Name	Function
1	2	EN	Chip enable pin. Active high
2	5	GND	Ground pin
3	4	LX	Switch output pin
4	3	VIN	Power supply
5	6	FB	Feedback voltage of output
_	1	NC	No internal connection



### **Functional Block Diagram**



## Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Ratir	ng	Unit
V <sub>IN</sub>	Input Voltage for the MOSFET Switch 0 to 6.0		6.0	V
V <sub>EN</sub>	Enable Input Voltage	-0.3 to \	/ <sub>IN</sub> +0.3	V
I <sub>LX</sub>	LX Pin Switch Current	1.	8	Α
		SOT-23-5	0.4	
P <sub>D</sub>	Power Dissipation (On PCB, T <sub>A</sub> = +25°C)	W-DFN2020-6 (Type US)	1.89	W
		SOT-23-5	250	°C/W
θЈА	Thermal Resistance (Junction to Ambient, Simulation)	W-DFN2020-6 (Type US)	53	
		SOT-23-5	130	
θ <sub>JC</sub>	Thermal Resistance (Junction to Case, Simulation)	W-DFN2020-6 (Type US)	25	°C/W
TJ	Operating Junction Temperature	+1:	+155	
T <sub>STG</sub>	Storage Temperature	-55 to +150		°C
T <sub>OP</sub>	Operating Temperature	-40 to +85		°C
V <sub>MM</sub>	ESD (Machine Model)	200		V
V <sub>HBM</sub>	ESD (Human Body Model)	20	00	V

Note 4: Stresses greater than those listed under "Absolute Maximum Ratings" can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods can affect device reliability.



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**AP3417C** 

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Unit
V <sub>IN</sub>	Supply Input Voltage	2.5	5.5	V
T <sub>A</sub>	Operating Ambient Temperature	-40	+85	°C
TJ	Operating Junction Temperature	-40	+125	°C

 $\textbf{Electrical Characteristics} \ (@V_{IN} = V_{EN} = 5V, \ V_{OUT} = 1.2V, \ V_{FB} = 0.6V, \ L = 2.2 \mu H, \ C_{IN} = 4.7 \mu F, \ C_{OUT} = 10 \mu F, \ T_A = +25 ^{\circ} C, \ unless \ otherwise specified.)$ 

Symbol	Parameters	Conditions	Min	Тур	Max	Unit
V <sub>IN</sub>	Input Voltage Range	_	2.5		5.5	V
loff	Shutdown Current	V <sub>EN</sub> = 0		<b>—</b>	0.1	μA
I <sub>ON</sub>	Active Current	V <sub>FB</sub> = 0.55V	7-1	220	-	μA
V <sub>FB</sub>	Regulated Feedback Voltage	_	0.588	0.6	0.612	V
ΔVουτ/Vουτ	Regulated Output Voltage Accuracy	V <sub>IN</sub> = 2.5V to 5.5V, I <sub>OUT</sub> = 0 to 1.0A	-3		3	%
I <sub>PK</sub>	Peak Inductor Current	- (1)	1.5	1.9	/ –	Α
fosc	Oscillator Frequency	V <sub>IN</sub> = 2.5V to 5.5V	1.2	1.5	1.8	MHz
R <sub>DS(ON)P</sub>	PMOSFET R <sub>DS(ON)</sub>	V <sub>IN</sub> = 5V	,	200	_	mΩ
R <sub>DS(ON)N</sub>	NMOSFET R <sub>DS(ON)</sub>	V <sub>IN</sub> = 5V	/	200	_	mΩ
V <sub>EN_H</sub>	EN High Level Input Voltage		1.5	_	_	V
V <sub>EN_L</sub>	EN Low Level Input Voltage	77	\ <del>-</del> /	_	0.4	V
I <sub>EN</sub>	EN Input Current	77	7	_	0.1	μA
t <sub>SS</sub>	Soft Start Time	-	<b>/</b> –	400	_	μs
D <sub>MAX</sub>	Maximum Duty Cycle	Z , \ \	100	_	_	%
	Hadaa Valla Khadaa	Rising	_	2.3	_	
V <sub>U</sub> VLO	Under Voltage Lock Out Threshold	Falling	_	2.1	_	V
		Hysteresis	_	0.2	_	
T <sub>SD</sub>	Thermal Shutdown	Hysteresis = +30°C	_	+155	+160	°C



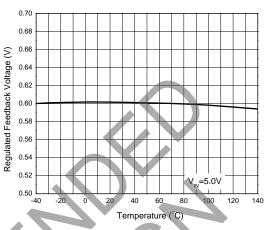


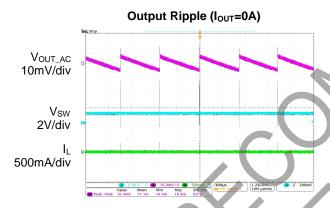
### Performance Characteristics (@ $V_{IN} = 5V$ , $T_A = +25$ °C, unless otherwise specified.)

## 

Output Current (A)

# Regulated Feedback Voltage vs. Temperature

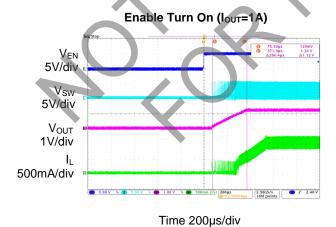




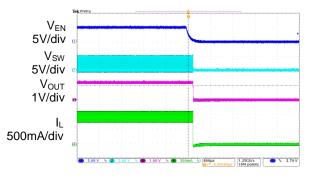
## Output Ripple (I<sub>OUT</sub>=1A)



Time 800µs/div



Enable Turn Off (Iout=1A)

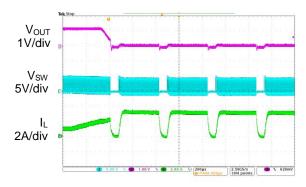


Time 800µs/div



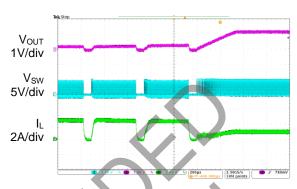
Performance Characteristics (continued) (@V<sub>IN</sub> = 5V, T<sub>A</sub> = +25°C, unless otherwise specified.)

### Short Circuit Protection (I<sub>OUT</sub>=1A)



Time 200µs/div

### Short Circuit Protection Recovery (I<sub>OUT</sub>=1A)



Time 200µs/div

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**AP3417C** 

### **Application Information**

Typical application circuit is shown in the *Typical Applications Circuit* and for the circuit parameters setting please refers to the following descriptions.

#### Under Voltage Lockout (UVLO) Circuit

When the  $V_{IN}$  drops lower than the UVLO detector threshold, the UVLO circuit starts to operate,  $V_{REF}$  stops, and high-side switch and low-side switch built-in switch transistors turn "OFF". As a result,  $V_{OUT}$  drops according to the  $C_{OUT}$  capacitance value and the load. When the  $V_{IN}$  is rising higher than UVLO released voltage, the IC will restart the operation.

#### **Short Circuit Protection and Recovery**

When the AP3417C output node is shorted to GND that V<sub>FB</sub> drops under 0.42V, AP3417C will enter hiccup mode to protect itself. If short circuit is removed, and V<sub>FB</sub> rises over 0.42V, the AP3417C recovers to normal operation again. If the AP3417C reaches OCP threshold while short circuit, the AP3417C will enters cycle by cycle current limit mode until the current under OCP threshold.

#### **Over Temperature Protection**

The internal thermal temperature protection circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When the junction temperature exceeds +160°C, it shuts down the internal control circuit and switching power MOSFET. The AP3417C will restart automatically under the control of soft start circuit when the junction temperature decreases to +145°C.

#### **Setting the Output Voltage**

The output voltage can be adjusted from 0.6V to 0.9\*V<sub>IN</sub> using an external resistor divider. Table 1 shows a list of resistor selections for common output voltages. Resistor R1 is selected based on a design tradeoff between efficiency and output voltage accuracy. For high values of R1 there is less current consumption in the feedback network. However the tradeoff is output voltage accuracy due to the bias current in the error amplifier. Meanwhile, the input capacitor should close to IC for preventing unexpected influences.

V <sub>OUT</sub> (V)	R1 (kΩ)	R2 (kΩ)	L (µH)
3.3	450	100	2.2
2.5	320	100	2.2
1.8	200	100	2.2
1.2	100	100	2.2
1.0	66	100	2.2

Table1. Resistor Selection for Common Output

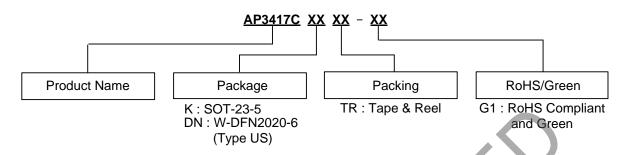
#### **Enable Control Input**

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Force this pin voltage above 1.5V enables the chip, and below 0.4V shuts down the device. When using this function to control input, please note the following information. Pay attention to input voltage, if input voltage is less than 5.2V, all functions work well without other concerns. If input voltage is higher than 5.2V, please confirm that EN pin must be connected to  $V_{IN}$  directly without the capacitor from EN to GND.

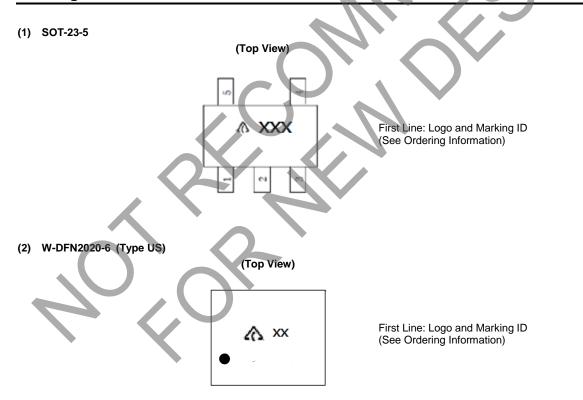


### **Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing
SOT-23-5	-40 to +85°C	AP3417CKTR-G1	G4I	3000 / Tape & Reel
W-DFN2020-6 (Type US)	-40 to +85°C	AP3417CDNTR-G1	ВН	3000 / Tape & Reel

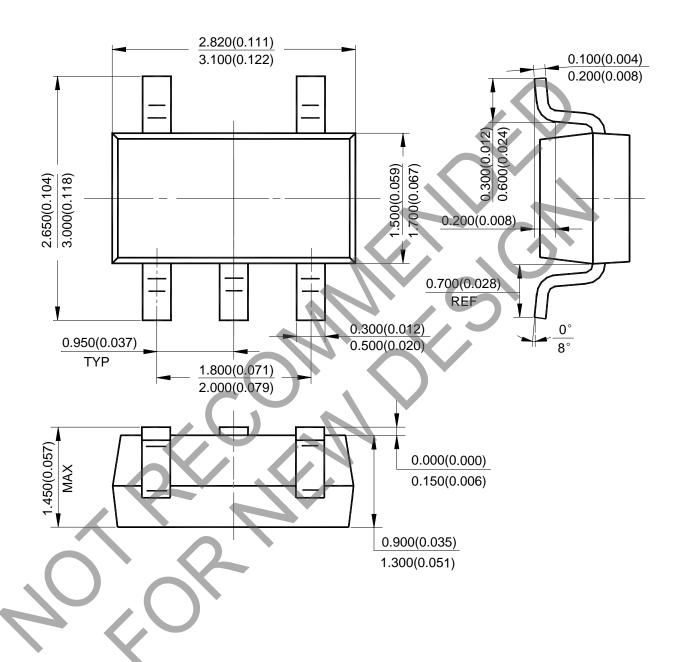
# **Marking Information**





## Package Outline Dimensions (All dimensions in mm(inch).)

### (1) Package Type: SOT-23-5

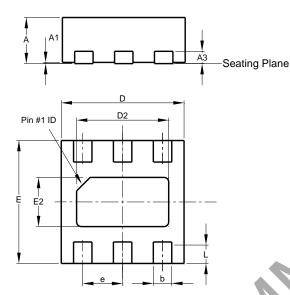




### Package Outline Dimensions (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (2) Package Type: W-DFN2020-6 (Type US)

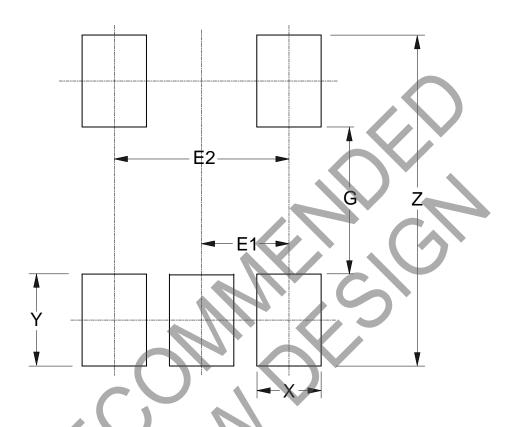


W-DFN2020-6 (Type US)				
Dim	Min	Max	Тур	
Α	0.70	0.80	0.75	
A1	0.00	0.05		
A3		0.20 RE		
b	0.25	0.35	0.30	
D	1.95	2.075	2.00	
D2	1.35	1.60	1.50	
E	1.95	2.075	2.00	
E2	0.65	0.90	0.80	
е	0.65 BSC			
L	0.25	0.45	0.35	
All Dimensions in mm				



# **Suggested Pad Layout**

### (1) Package Type: SOT-23-5



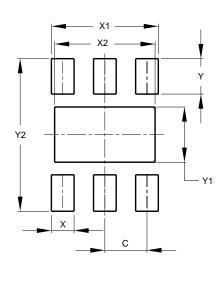
Dimensions	Z	G	X	Y	E1	E2
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



### Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (2) Package Type: W-DFN2020-6 (Type US)



Dimensions	Value (in mm)	
С	0.650	
X	0.350	
X1	1.650	
X2	1.550	
Υ	0.545	
Y1	0.850	
Y2	2.350	



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AP3417C

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